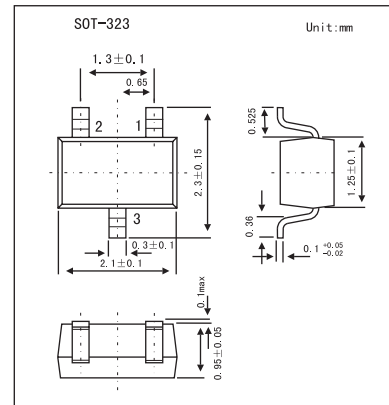


BAT64W;BAT64-04W BAT64-05W;BAT64-06W

■ Features

- For low-loss, fast-recovery, meter protection, bias isolation and clamping applications
- Integrated diffused guard ring
- Low forward voltage



■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Value	Unit
Diode reverse voltage	V _R	40	V
Forward current	I _F	250	mA
Average forward current (50/60Hz, sinus)	I _{FAV}	120	mA
Surge forward current (t < 100ms)	I _{FSM}	800	mA
Total power dissipation BAT 64W, T _s ≤ 120 °C	P _{tot}	250	mW
Total power dissipation BAT64-04/06W, T _s ≤ 111 °C	P _{tot}	250	mW
Total power dissipation BAR 64-05W, T _s ≤ 104 °C	P _{tot}	250	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-50 to+150	°C
Junction - ambient (Note 1) BAT 64W	R _{thJA}	≤ 255	K/W
Junction - ambient (Note 1) BAT 64-04/06W	R _{thJA}	≤ 290	
Junction - ambient (Note 1) BAT 64-05W	R _{thJA}	≤ 455	
Junction - soldering point BAT 64W	R _{thJS}	≤ 120	K/W
Junction - soldering point BAT 64-04/06W	R _{thJS}	≤ 155	
Junction - soldering point BAT 64-05W	R _{thJS}	≤ 185	

Note

1.Package mounted on epoxy pcb 40mm × 40mm × 1.5mm / 6cm² Cu



**BAT64W;BAT64-04W
BAT64-05W;BAT64-06W**

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse current	I _R	V _R = 30 V			2	μ A
		V _R = 30 V, T _A = 85°C			200	
Forward voltage	V _F	I _F = 1 mA		320	350	mV
		I _F = 10 mA		380	430	
		I _F = 30 mA		440	520	
		I _F = 100 mA		570	750	
Diode capacitance	C _T	V _R = 1 V, f = 1 MHz		4	6	pF

■ Marking

Type	BAT64W	BAT64-04W	BAT64-05W	BAT64-06W
Marking	63s	64s	65s	66s